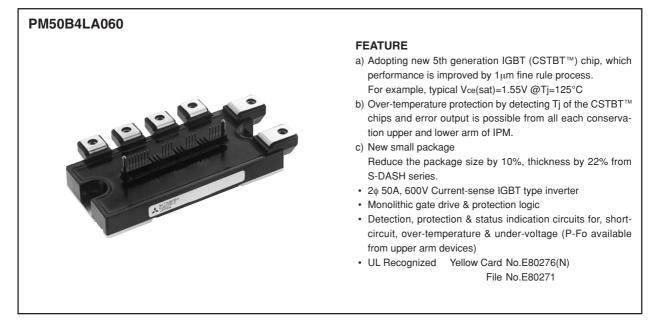
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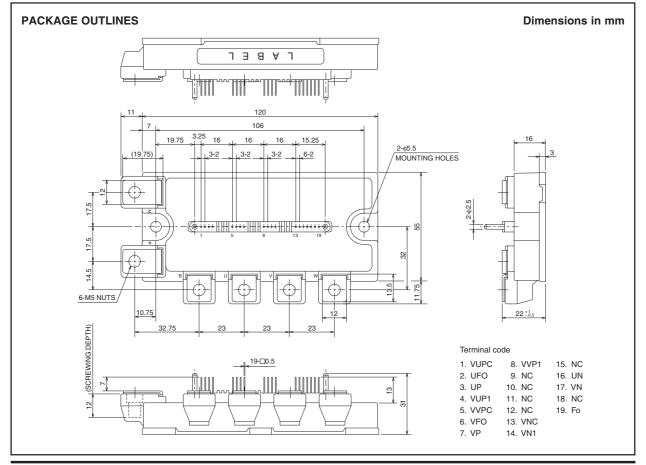
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FLAT-BASE TYPE INSULATED PACKAGE



APPLICATION

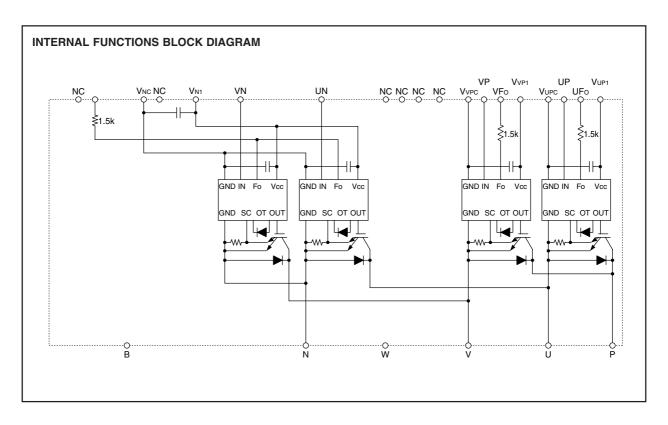
Photo voltaic power conditioner





Jun. 2007

FLAT-BASE TYPE INSULATED PACKAGE



MAXIMUM RATINGS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

Symbol	Parameter	Condition	Ratings	Unit
VCES	Collector-Emitter Voltage	VD = 15V, VCIN = 15V	600	V
±IC	Collector Current	$TC = 25^{\circ}C$	50	Α
±ICP	Collector Current (Peak)	$TC = 25^{\circ}C$	100	A
Pc	Collector Dissipation	$Tc = 25^{\circ}C$	134	W
Tj	Junction Temperature		<i>–</i> 20 ~ +150	°C

CONTROL PART

Symbol	Parameter	Condition	Ratings	Unit
VD	Supply Voltage	Applied between : VUP1-VUPC	20	v
	Supply Voltage	VVP1-VVPC, VN1-VNC	20	v
VCIN	Input Voltage	Applied between : UP-VUPC, VP-VVPC	20	v
VOIN		UN • VN-VNC	20	v
VFO	Fault Output Supply Voltage	Applied between : UFO-VUPC, VFO-VVPC, FO-VNC	20	V
IFO	Fault Output Current	Sink current at UFO, VFO, FO terminals	20	mA



FLAT-BASE TYPE INSULATED PACKAGE

TOTAL SYSTEM

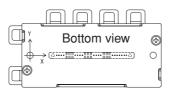
Symbol	Parameter	Condition	Ratings	Unit
VCC(PROT)	Supply Voltage Protected by SC	$VD = 13.5 \sim 16.5V$, Inverter Part, Tj = +125°C Start	450	V
VCC(surge)	Supply Voltage (Surge)	Applied between : P-N, Surge value	500	V
Tstg	Storage Temperature		-40 ~ +125	°C
Viso	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base, AC 1 min.	2500	Vrms

THERMAL RESISTANCES

Symbol Parameter		Condition					
				Min.	Тур.	Max.	Unit
Rth(j-c)Q	Junction to case Thermal	Inverter IGBT part (per 1/4 module) (Not	ote-1)	_	_	0.93	
Rth(j-c)F	Resistances	Inverter FWDi part (per 1/4 module) (Not	ote-1)	_	_	1.57	°C/W
Data (a. 6)	Contact Thermal Resistance	Case to fin, (per 1 module)				— 0.038	C/ VV
Rth(c-f)		Thermal grease applied (Not	ote-1)	—			

(Note-1) Tc (under the chip) measurement point is below.

(unit : mm)									
arm		UP		VP		UN		V	N
axis		IGBT	FWDi	IGBT	FWDi	IGBT	FWDi	IGBT	FWDi
Х		30.2	30.7	59.0	59.5	38.2	39.8	50.9	49.4
Y		-7.9	-1.1	-7.9	-1.1	6.5	-0.3	6.5	-0.3



ELECTRICAL CHARACTERISTICS (Tj = 25° C, unless otherwise noted) **INVERTER PART**

		Condition			Unit		
Symbol	Parameter	Condition		Min.	Тур.	Max.	Unit
	Collector-Emitter	VD = 15V, IC = 50A	Tj = 25°C	—	1.7	2.3	v
VCE(sat)	Saturation Voltage	VCIN = 0V (Fig. 1)	Tj = 125°C	—	1.55	2.0	v
VEC	FWDi Forward Voltage	-IC = 50A, VD = 15V, VCIN = 15V	(Fig. 2)	—	2.2	3.3	V
ton				0.3	0.7	1.4	
trr		VD = 15V, VCIN = 0V↔15V		—	0.1	0.2	1
tc(on)	Switching Time	$V_{CC} = 300V, I_{C} = 50A$		—	0.2	0.4	μs
toff		$T_j = 125^{\circ}C$	(Fig. 0.4)	—	0.9	1.8	1
tc(off)		Inductive Load	(Fig. 3,4)	—	0.2	0.2	
1050	Collector-Emitter		Tj = 25°C	_	_	1	
ICES	Cutoff Current	VCE = VCES, VCIN = 15V (Fig. 5)	Tj = 125°C	—	—	10	mA



FLAT-BASE TYPE INSULATED PACKAGE

CONTROL PART

Cumhal	Demonstern	Parameter Condition			11-24		
Symbol	ymbol Parameter Cor		aition		Тур.	Max.	Unit
ID	Circuit Current	VD = 15V, VCIN = 15V	VN1-VNC	—	10	20	
			V*P1-V*PC	—	5	10	mA
Vth(ON)	Input ON Threshold Voltage	Applied between : UP-VUPC, VP-VVPC		1.2	1.5	1.8	V
Vth(OFF)	Input OFF Threshold Voltage	UN • VN-VNC		1.7	2.0	2.3	v
SC	Short Circuit Trip Level	-20 ≤ Tj ≤ 125°C, VD = 15V	(Fig. 3,6)	100	_	_	Α
toff(SC)	Short Circuit Current Delay Time	VD = 15V	(Fig. 3,6)	_	0.2	_	μS
OT	Our Transaction Durito stiller	VD = 15V	Trip level	135	145	_	°C
OTr	Over Temperature Protection	Detect Tj of IGBT chip	Reset level	_	125	_	
UV	Supply Circuit Under-Voltage	–20 ≤ Ti ≤ 125°C	Trip level	11.5	12.0	12.5	v
UVr	Protection	-20 ≤ 1] ≤ 125 C	Reset level	_	12.5	_	v
IFO(H)	Fault Output Current	VD = 15V. VFO = 15V	(Note-2)	_	_	0.01	mA
IFO(L)		VD = 15V, VFO = 15V	(11018-2)	_	10	15	IIIA
tFO	Minimum Fault Output Pulse Width	VD = 15V	(Note-2)	1.0	1.8	_	ms

(Note-2) Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

MECHANICAL RATINGS AND CHARACTERISTICS

Demonster		Condition		Limits			Unit
Symbol	Symbol Parameter Condition		Min.	Тур.	Max.	Unit	
—	Mounting torque	Main terminal	screw : M5	2.5	3.0	3.5	N۰m
	Mounting torque	Mounting part	screw : M5	2.5	3.0	3.5	N•m
_	Weight	_		_	380	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Condition		Recommended value	Unit
Vcc	Supply Voltage	Applied across P-N terminals		<u>≤</u> 450	V
VD	Control Supply Voltage	Applied between : VUP1-VUPC, VVP1-VVPC VN1-VNC	(Note-3)	15 ± 1.5	V
VCIN(ON)	Input ON Voltage	Applied between : UP-VUPC, VP-VVPC		≤ 0.8	v
VCIN(OFF)	Input OFF Voltage	UN • VN-VNC		≥ 9.0	v
fрwм	PWM Input Frequency	Using Application Circuit of Fig. 8		≤ 20	kHz
tdead	Arm Short-through Blocking Time	For IPM's each input signals	(Fig. 7)	≥ 2.0	μs

(Note-3) With ripple satisfying the following conditions : dv/dt swing < $\pm 5V/\mu s$, Variation < 2V peak to peak



VCE

90%

(toff= td(off) + tf)

10% -

td(off)

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FLAT-BASE TYPE INSULATED PACKAGE

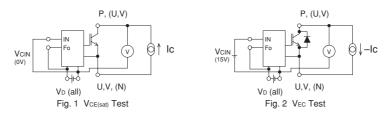
PRECAUTIONS FOR TESTING

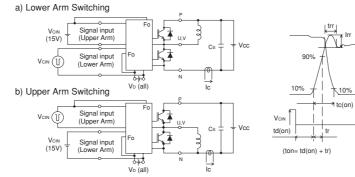
1. Before appling any control supply voltage (VD), the input terminals should be pulled up by resistores, etc. to their corresponding supply voltage and each input signal should be kept off state.

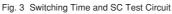
After this, the specified ON and OFF level setting for each input signal should be done.

2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above VCES rating of the device.

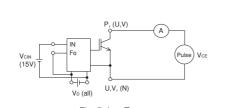
(These test should not be done by using a curve tracer or its equivalent.)



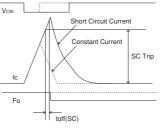




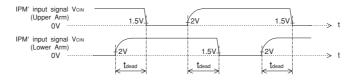












1.5V: Input on threshold voltage Vth(on) typical value, 2V: Input off threshold voltage Vth(off) typical value

Fig. 7 Dead Time Measurement Point Example



FLAT-BASE TYPE INSULATED PACKAGE

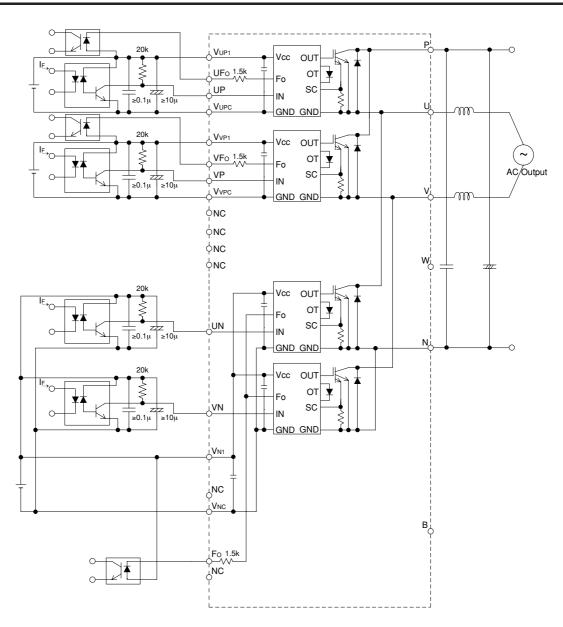


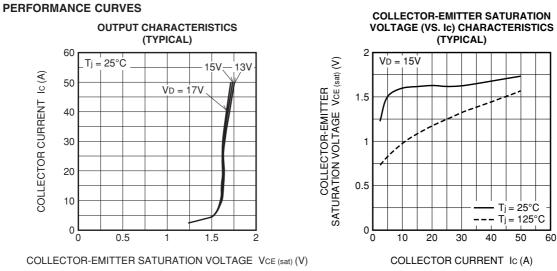
Fig. 8 Application Example Circuit

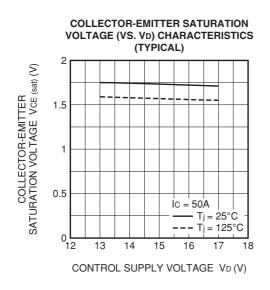
NOTES FOR STABLE AND SAFE OPERATION ;

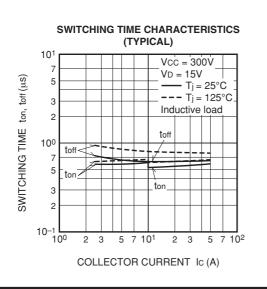
- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers: tPLH, tPHL ≤ 0.8µs, Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- Use 3 isolated control power supplies (VD). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.

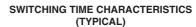


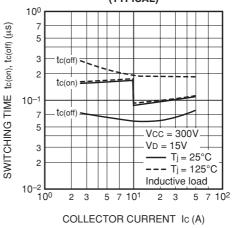
FLAT-BASE TYPE **INSULATED PACKAGE**

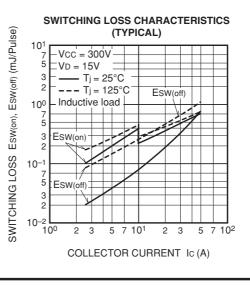






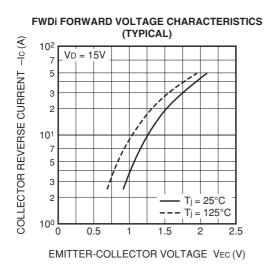




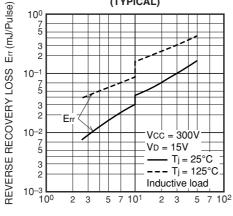


MITSUBISHI ELECTRIC

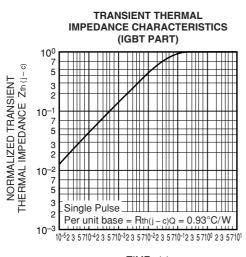
FLAT-BASE TYPE INSULATED PACKAGE



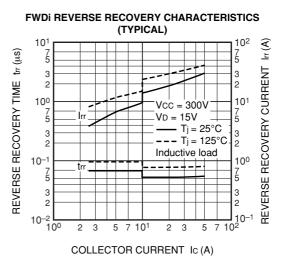
FWDI REVERSE RECOVERY LOSS CHARACTERISTICS

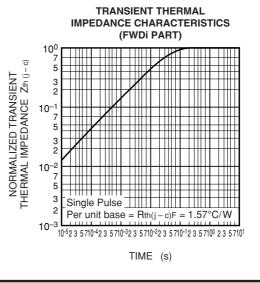


COLLECTOR REVERSE CURRENT -Ic (A)



TIME (s)







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